

## FEATURES

**2.1  $\Omega$  on resistance**  
**0.5  $\Omega$  maximum on-resistance flatness at 25°C**  
**Up to 390 mA continuous current**  
**Fully specified at  $+12$  V,  $\pm 15$  V,  $\pm 5$  V**  
**No  $V_L$  supply required**  
**3 V logic-compatible inputs**  
**Rail-to-rail operation**  
**8-lead MSOP and 8-lead, 3 mm  $\times$  2 mm LFCSP**

## APPLICATIONS

**Automatic test equipment**  
**Data acquisition systems**  
**Battery-powered systems**  
**Relay replacements**  
**Sample-and-hold systems**  
**Audio signal routing**  
**Video signal routing**  
**Communication systems**

## GENERAL DESCRIPTION

The **ADG1419** is a monolithic iCMOS® device containing a single-pole/double-throw (SPDT) switch. An EN input on the LFCSP is used to enable or disable the device. When disabled, all channels are switched off.

The industrial CMOS (iCMOS) modular manufacturing process combines high voltage, complementary metal-oxide semiconductor (CMOS) and bipolar technologies. It enables the development of a wide range of high performance analog ICs capable of 33 V operation in a footprint that no other generation of high voltage parts has achieved. Unlike analog ICs using conventional CMOS processes, iCMOS components can tolerate high supply voltages while providing increased performance, dramatically lower power consumption, and reduced package size.

The on-resistance profile is very flat over the full analog input range, ensuring excellent linearity and low distortion when switching audio signals. The iCMOS construction ensures ultralow power dissipation, making the part ideally suited for portable and battery-powered instruments.

## FUNCTIONAL BLOCK DIAGRAMS

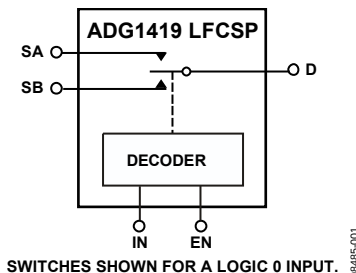


Figure 1. 8-Lead LFCSP (CP-8-4)

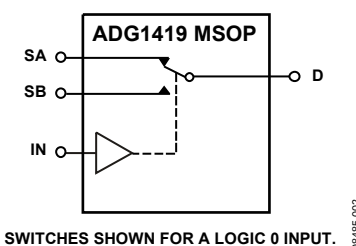


Figure 2. 8-Lead MSOP (RM-8)

Each switch conducts equally well in both directions when on and has an input signal range that extends to the supplies. In the off condition, signal levels up to the supplies are blocked. The **ADG1419** exhibits break-before-make switching action for use in multiplexer applications.

## PRODUCT HIGHLIGHTS

1. 2.4  $\Omega$  maximum on resistance at 25°C.
2. Minimum distortion.
3. 3 V logic-compatible digital inputs:  $V_{INH} = 2.0$  V,  $V_{INL} = 0.8$  V.
4. No  $V_L$  logic power supply required.
5. 8-lead MSOP and 8-lead, 3 mm  $\times$  2 mm LFCSP.

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REVISION HISTORY

|                                                |   |
|------------------------------------------------|---|
| 6/2016—Rev. 0 to Rev. A                        |   |
| Changes to Table 7 .....                       | 8 |
| Deleted Table 9; Renumbered Sequentially ..... | 8 |
| Change to Figure 6 .....                       | 9 |

10/2009—Revision 0: Initial Version

## SPECIFICATIONS

## ±15 V DUAL SUPPLY

$V_{DD} = +15\text{ V} \pm 10\%$ ,  $V_{SS} = -15\text{ V} \pm 10\%$ , GND = 0 V, unless otherwise noted.

Table 1.

| Parameter                                                | 25°C  | −40°C to +85°C | −40°C to +125°C                    | Unit                                                                                   | Test Conditions/Comments                                                                                                                                                  |                                                                           |
|----------------------------------------------------------|-------|----------------|------------------------------------|----------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------|
| ANALOG SWITCH                                            |       |                |                                    |                                                                                        |                                                                                                                                                                           |                                                                           |
| Analog Signal Range                                      |       |                | V <sub>DD</sub> to V <sub>SS</sub> | V                                                                                      |                                                                                                                                                                           |                                                                           |
| On Resistance, R <sub>ON</sub>                           | 2.1   | 2.8            | 3.2                                | Ω typ                                                                                  | V <sub>S</sub> = ±10 V, I <sub>S</sub> = −10 mA; see Figure 22<br>V <sub>DD</sub> = +13.5 V, V <sub>SS</sub> = −13.5 V<br>V <sub>S</sub> = ±10 V, I <sub>S</sub> = −10 mA |                                                                           |
| On-Resistance Match Between Channels, ΔR <sub>ON</sub>   | 2.4   |                |                                    | Ω max                                                                                  |                                                                                                                                                                           |                                                                           |
|                                                          | 0.05  |                |                                    | Ω typ                                                                                  |                                                                                                                                                                           |                                                                           |
| On-Resistance Flatness, R <sub>FLAT (ON)</sub>           | 0.2   | 0.25           | 0.3                                | Ω max                                                                                  | V <sub>S</sub> = ±10 V, I <sub>S</sub> = −10 mA                                                                                                                           |                                                                           |
|                                                          | 0.4   |                |                                    | Ω typ                                                                                  |                                                                                                                                                                           |                                                                           |
|                                                          | 0.5   |                |                                    | Ω max                                                                                  |                                                                                                                                                                           |                                                                           |
| LEAKAGE CURRENTS                                         |       |                |                                    |                                                                                        |                                                                                                                                                                           |                                                                           |
| Source Off Leakage, I <sub>S</sub> (Off)                 | ±0.1  | ±2             | ±75                                | nA typ                                                                                 | V <sub>DD</sub> = +16.5 V, V <sub>SS</sub> = −16.5 V<br>V <sub>S</sub> = ±10 V, V <sub>S</sub> = ±10 V; see Figure 23                                                     |                                                                           |
| Drain Off Leakage, I <sub>D</sub> (Off)                  | ±0.5  |                |                                    | nA max                                                                                 |                                                                                                                                                                           |                                                                           |
|                                                          | ±0.2  |                |                                    | nA typ                                                                                 |                                                                                                                                                                           | V <sub>S</sub> = ±10 V, V <sub>S</sub> = ±10 V; see Figure 23             |
| Channel On Leakage, I <sub>D</sub> , I <sub>S</sub> (On) | ±0.6  | ±3             | ±100                               | nA max                                                                                 |                                                                                                                                                                           |                                                                           |
|                                                          | ±0.2  |                | nA typ                             | V <sub>S</sub> = V <sub>D</sub> = ±10 V; see Figure 24                                 |                                                                                                                                                                           |                                                                           |
|                                                          | ±1    | ±3             | ±100                               |                                                                                        | nA max                                                                                                                                                                    |                                                                           |
| DIGITAL INPUTS                                           |       |                |                                    |                                                                                        |                                                                                                                                                                           |                                                                           |
| Input High Voltage, V <sub>INH</sub>                     |       |                | 2.0                                | V min                                                                                  | V <sub>IN</sub> = V <sub>GND</sub> or V <sub>DD</sub>                                                                                                                     |                                                                           |
| Input Low Voltage, V <sub>INL</sub>                      |       |                | 0.8                                | V max                                                                                  |                                                                                                                                                                           |                                                                           |
| Input Current, I <sub>INL</sub> or I <sub>INH</sub>      | 0.005 |                | ±0.1                               | μA typ                                                                                 |                                                                                                                                                                           |                                                                           |
|                                                          |       |                |                                    | μA max                                                                                 |                                                                                                                                                                           |                                                                           |
| Digital Input Capacitance, C <sub>IN</sub>               | 4     |                |                                    | pF typ                                                                                 |                                                                                                                                                                           |                                                                           |
| DYNAMIC CHARACTERISTICS <sup>1</sup>                     |       |                |                                    |                                                                                        |                                                                                                                                                                           |                                                                           |
| Transition Time, t <sub>TRANSITION</sub>                 | 130   | 190            | 220                                | ns typ                                                                                 | R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF<br>V <sub>S</sub> = +10 V; see Figure 25                                                                                   |                                                                           |
|                                                          | 155   |                |                                    | ns max                                                                                 |                                                                                                                                                                           |                                                                           |
| t <sub>ON</sub> (EN)                                     | 85    |                |                                    | ns typ                                                                                 |                                                                                                                                                                           | 140                                                                       |
|                                                          | 110   | ns max         |                                    |                                                                                        |                                                                                                                                                                           |                                                                           |
| t <sub>OFF</sub> (EN)                                    | 115   | ns typ         | 180                                | R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF<br>V <sub>S</sub> = 10 V; see Figure 27 |                                                                                                                                                                           |                                                                           |
|                                                          | 140   | ns max         |                                    |                                                                                        |                                                                                                                                                                           |                                                                           |
| Break-Before-Make Time Delay, t <sub>D</sub>             | 15    | 160            |                                    |                                                                                        | 8                                                                                                                                                                         | ns typ                                                                    |
|                                                          |       |                |                                    | ns min                                                                                 |                                                                                                                                                                           |                                                                           |
| Charge Injection                                         | −16   |                |                                    | pC typ                                                                                 | V <sub>S</sub> = 0 V, R <sub>S</sub> = 0 Ω, C <sub>L</sub> = 1 nF;<br>see Figure 28                                                                                       |                                                                           |
| Off Isolation                                            | −64   |                |                                    | dB typ                                                                                 |                                                                                                                                                                           | R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 5 pF, f = 1 MHz;<br>see Figure 29 |
| Channel-to-Channel Crosstalk                             | −64   |                |                                    | dB typ                                                                                 |                                                                                                                                                                           |                                                                           |
| Total Harmonic Distortion Plus Noise (THD + N)           | 0.016 |                |                                    | % typ                                                                                  | R <sub>L</sub> = 10 kΩ, 5 V rms, f = 20 Hz to 20 kHz; see Figure 32                                                                                                       |                                                                           |
| −3 dB Bandwidth                                          | 135   |                |                                    | MHz typ                                                                                |                                                                                                                                                                           | R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 5 pF; see Figure 31               |
| Insertion Loss                                           | 0.16  |                |                                    | dB typ                                                                                 |                                                                                                                                                                           |                                                                           |
| C <sub>S</sub> (Off)                                     | 19    |                |                                    | pF typ                                                                                 | f = 1 MHz; V <sub>S</sub> = 0 V                                                                                                                                           |                                                                           |
| C <sub>D</sub> (Off)                                     | 44    |                |                                    | pF typ                                                                                 |                                                                                                                                                                           | f = 1 MHz; V <sub>S</sub> = 0 V                                           |
| C <sub>D</sub> , C <sub>S</sub> (On)                     | 114   |                |                                    | pF typ                                                                                 |                                                                                                                                                                           |                                                                           |

| Parameter               | 25°C  | –40°C to +85°C | –40°C to +125°C    | Unit                                   | Test Conditions/Comments                              |
|-------------------------|-------|----------------|--------------------|----------------------------------------|-------------------------------------------------------|
| POWER REQUIREMENTS      |       |                |                    |                                        | $V_{DD} = +16.5\text{ V}$ , $V_{SS} = -16.5\text{ V}$ |
| $I_{DD}$                | 0.002 |                | 1.0                | $\mu\text{A typ}$<br>$\mu\text{A max}$ | Digital inputs = 0 V or $V_{DD}$                      |
| $I_{DD}$ , 8-Lead MSOP  | 58    |                | 95                 | $\mu\text{A typ}$<br>$\mu\text{A max}$ | Digital inputs = 5 V                                  |
| $I_{DD}$ , 8-Lead LFCSP | 120   |                | 190                | $\mu\text{A typ}$<br>$\mu\text{A max}$ | Digital inputs = 5 V                                  |
| $I_{SS}$                | 0.002 |                | 1.0                | $\mu\text{A typ}$<br>$\mu\text{A max}$ | Digital inputs = 0 V, 5 V, or $V_{DD}$                |
| $V_{DD}/V_{SS}$         |       |                | $\pm 4.5/\pm 16.5$ | V min/max                              | Ground = 0 V                                          |

<sup>1</sup> Guaranteed by design, not subject to production test.

## +12 V SINGLE SUPPLY

$V_{DD} = 12\text{ V} \pm 10\%$ ,  $V_{SS} = 0\text{ V}$ , GND = 0 V, unless otherwise noted.

Table 2.

| Parameter                                             | 25°C      | –40°C to +85°C | –40°C to +125°C | Unit                                   | Test Conditions/Comments                                                        |
|-------------------------------------------------------|-----------|----------------|-----------------|----------------------------------------|---------------------------------------------------------------------------------|
| ANALOG SWITCH                                         |           |                |                 |                                        |                                                                                 |
| Analog Signal Range                                   |           |                | 0 V to $V_{DD}$ | V                                      |                                                                                 |
| On Resistance, $R_{ON}$                               | 4         |                |                 | $\Omega$ typ                           | $V_S = 0\text{ V to }10\text{ V}$ , $I_S = -10\text{ mA}$ ; see Figure 22       |
|                                                       | 4.6       | 5.5            | 6.2             | $\Omega$ max                           | $V_{DD} = +10.8\text{ V}$ , $V_{SS} = 0\text{ V}$                               |
| On-Resistance Match Between Channels, $\Delta R_{ON}$ | 0.08      |                |                 | $\Omega$ typ                           | $V_S = 0\text{ V to }10\text{ V}$ , $I_S = -10\text{ mA}$                       |
|                                                       | 0.25      | 0.3            | 0.35            | $\Omega$ max                           |                                                                                 |
| On-Resistance Flatness, $R_{FLAT(ON)}$                | 1.2       |                |                 | $\Omega$ typ                           | $V_S = 0\text{ V to }10\text{ V}$ , $I_S = -10\text{ mA}$                       |
|                                                       | 1.5       | 1.75           | 1.9             | $\Omega$ max                           |                                                                                 |
| LEAKAGE CURRENTS                                      |           |                |                 |                                        | $V_{DD} = +13.2\text{ V}$ , $V_{SS} = 0\text{ V}$                               |
| Source Off Leakage, $I_S$ (Off)                       | $\pm 0.1$ |                |                 | nA typ                                 | $V_S = 1\text{ V}/10\text{ V}$ , $V_D = 10\text{ V}/1\text{ V}$ ; see Figure 23 |
|                                                       | $\pm 0.5$ | $\pm 2$        | $\pm 75$        | nA max                                 |                                                                                 |
| Drain Off Leakage, $I_D$ (Off)                        | $\pm 0.2$ |                |                 | nA typ                                 | $V_S = 1\text{ V}/10\text{ V}$ , $V_D = 10\text{ V}/1\text{ V}$ ; see Figure 23 |
|                                                       | $\pm 0.6$ | $\pm 3$        | $\pm 100$       | nA max                                 |                                                                                 |
| Channel On Leakage, $I_D$ , $I_S$ (On)                | $\pm 0.2$ |                |                 | nA typ                                 | $V_S = V_D = 1\text{ V or }10\text{ V}$ ; see Figure 24                         |
|                                                       | $\pm 1$   | $\pm 3$        | $\pm 100$       | nA max                                 |                                                                                 |
| DIGITAL INPUTS                                        |           |                |                 |                                        |                                                                                 |
| Input High Voltage, $V_{INH}$                         |           |                | 2.0             | V min                                  |                                                                                 |
| Input Low Voltage, $V_{INL}$                          |           |                | 0.8             | V max                                  |                                                                                 |
| Input Current, $I_{INL}$ or $I_{INH}$                 | 0.005     |                |                 | $\mu\text{A typ}$<br>$\mu\text{A max}$ | $V_{IN} = V_{GND}$ or $V_{DD}$                                                  |
|                                                       |           |                | $\pm 0.1$       | $\mu\text{A max}$                      |                                                                                 |
| Digital Input Capacitance, $C_{IN}$                   | 4         |                |                 | pF typ                                 |                                                                                 |
| DYNAMIC CHARACTERISTICS <sup>1</sup>                  |           |                |                 |                                        |                                                                                 |
| Transition Time, $t_{TRANSITION}$                     | 200       |                |                 | ns typ                                 | $R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$                                      |
|                                                       | 255       | 265            | 370             | ns max                                 | $V_S = 8\text{ V}$ ; see Figure 25                                              |
| $t_{ON}$ (EN)                                         | 145       |                |                 | ns typ                                 | $R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$                                      |
|                                                       | 190       | 220            | 245             | ns max                                 | $V_S = 8\text{ V}$ ; see Figure 27                                              |
| $t_{OFF}$ (EN)                                        | 130       |                |                 | ns typ                                 | $R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$                                      |
|                                                       | 170       | 205            | 220             | ns max                                 | $V_S = 8\text{ V}$ ; see Figure 27                                              |
| Break-Before-Make Time Delay, $t_D$                   | 55        |                |                 | ns typ                                 | $R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$                                      |
|                                                       |           |                | 33              | ns min                                 | $V_{S1} = V_{S2} = 8\text{ V}$ ; see Figure 26                                  |
| Charge Injection                                      | 13        |                |                 | pC typ                                 | $V_S = 6\text{ V}$ , $R_S = 0\ \Omega$ , $C_L = 1\text{ nF}$ ; see Figure 28    |
| Off Isolation                                         | –60       |                |                 | dB typ                                 | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ , $f = 1\text{ MHz}$ ; see Figure 29   |

| Parameter                    | 25°C  | –40°C to +85°C | –40°C to +125°C | Unit              | Test Conditions/Comments                                                        |
|------------------------------|-------|----------------|-----------------|-------------------|---------------------------------------------------------------------------------|
| Channel-to-Channel Crosstalk | –60   |                |                 | dB typ            | $R_L = 50\ \Omega$ , $C_L = 5\ \text{pF}$ , $f = 1\ \text{MHz}$ ; see Figure 30 |
| –3 dB Bandwidth              | 95    |                |                 | MHz typ           | $R_L = 50\ \Omega$ , $C_L = 5\ \text{pF}$ ; see Figure 31                       |
| Insertion Loss               | 0.3   |                |                 | dB typ            | $R_L = 50\ \Omega$ , $C_L = 5\ \text{pF}$ , $f = 1\ \text{MHz}$ ; see Figure 31 |
| $C_S$ (Off)                  | 32    |                |                 | pF typ            | $f = 1\ \text{MHz}$ ; $V_S = 6\ \text{V}$                                       |
| $C_D$ (Off)                  | 72    |                |                 | pF typ            | $f = 1\ \text{MHz}$ ; $V_S = 6\ \text{V}$                                       |
| $C_D$ , $C_S$ (On)           | 123   |                |                 | pF typ            | $f = 1\ \text{MHz}$ ; $V_S = 6\ \text{V}$                                       |
| <b>POWER REQUIREMENTS</b>    |       |                |                 |                   |                                                                                 |
| $I_{DD}$                     | 0.001 |                |                 | $\mu\text{A}$ typ | $V_{DD} = 13.2\ \text{V}$<br>Digital inputs = 0 V or $V_{DD}$                   |
| $I_{DD}$ , 8-Lead MSOP       | 58    |                | 1.0             | $\mu\text{A}$ max |                                                                                 |
|                              |       |                |                 | $\mu\text{A}$ typ | Digital inputs = 5 V                                                            |
| $I_{DD}$ , 8-Lead LFCSP      | 120   |                | 95              | $\mu\text{A}$ max |                                                                                 |
|                              |       |                |                 | $\mu\text{A}$ typ | Digital inputs = 5 V                                                            |
|                              |       |                | 190             | $\mu\text{A}$ max |                                                                                 |
| $V_{DD}$                     |       |                | 5/16.5          | V min/max         | Ground = 0 V, $V_{SS} = 0\ \text{V}$                                            |

<sup>1</sup> Guaranteed by design, not subject to production test.

### ±5 V DUAL SUPPLY

$V_{DD} = +5\ \text{V} \pm 10\%$ ,  $V_{SS} = -5\ \text{V} \pm 10\%$ , GND = 0 V, unless otherwise noted.

**Table 3.**

| Parameter                                             | 25°C      | –40°C to +85°C | –40°C to +125°C      | Unit              | Test Conditions/Comments                                              |
|-------------------------------------------------------|-----------|----------------|----------------------|-------------------|-----------------------------------------------------------------------|
| <b>ANALOG SWITCH</b>                                  |           |                |                      |                   |                                                                       |
| Analog Signal Range                                   |           |                | $V_{DD}$ to $V_{SS}$ | V                 |                                                                       |
| On Resistance, $R_{ON}$                               | 4.5       |                |                      | $\Omega$ typ      | $V_S = \pm 4.5\ \text{V}$ , $I_S = -10\ \text{mA}$ ; see Figure 22    |
|                                                       | 5.2       | 6.2            | 7                    | $\Omega$ max      | $V_{DD} = +4.5\ \text{V}$ , $V_{SS} = -4.5\ \text{V}$                 |
| On-Resistance Match Between Channels, $\Delta R_{ON}$ | 0.1       |                |                      | $\Omega$ typ      | $V_S = \pm 4.5\ \text{V}$ , $I_S = -10\ \text{mA}$                    |
|                                                       | 0.3       | 0.35           | 0.4                  | $\Omega$ max      |                                                                       |
| On-Resistance Flatness, $R_{FLAT(ON)}$                | 1.3       |                |                      | $\Omega$ typ      | $V_S = \pm 4.5\ \text{V}$ , $I_S = -10\ \text{mA}$                    |
|                                                       | 1.6       | 1.85           | 2                    | $\Omega$ max      |                                                                       |
| <b>LEAKAGE CURRENTS</b>                               |           |                |                      |                   |                                                                       |
| Source Off Leakage, $I_S$ (Off)                       | $\pm 0.1$ |                |                      | nA typ            | $V_{DD} = +5.5\ \text{V}$ , $V_{SS} = -5.5\ \text{V}$                 |
|                                                       | $\pm 0.5$ | $\pm 2$        | $\pm 75$             | nA max            | $V_S = \pm 4.5\ \text{V}$ , $V_D = \mp 4.5\ \text{V}$ ; see Figure 23 |
| Drain Off Leakage, $I_D$ (Off)                        | $\pm 0.1$ |                |                      | nA typ            | $V_S = \pm 4.5\ \text{V}$ , $V_D = \mp 4.5\ \text{V}$ ; see Figure 23 |
|                                                       | $\pm 0.6$ | $\pm 3$        | $\pm 100$            | nA max            |                                                                       |
| Channel On Leakage, $I_D$ , $I_S$ (On)                | $\pm 0.1$ |                |                      | nA typ            | $V_S = V_D = \pm 4.5\ \text{V}$ ; see Figure 24                       |
|                                                       | $\pm 1$   | $\pm 3$        | $\pm 100$            | nA max            |                                                                       |
| <b>DIGITAL INPUTS</b>                                 |           |                |                      |                   |                                                                       |
| Input High Voltage, $V_{INH}$                         |           |                | 2.0                  | V min             |                                                                       |
| Input Low Voltage, $V_{INL}$                          |           |                | 0.8                  | V max             |                                                                       |
| Input Current, $I_{INL}$ or $I_{INH}$                 | 0.001     |                |                      | $\mu\text{A}$ typ | $V_{IN} = V_{GND}$ or $V_{DD}$                                        |
|                                                       |           |                | $\pm 0.1$            | $\mu\text{A}$ max |                                                                       |
| Digital Input Capacitance, $C_{IN}$                   | 4         |                |                      | pF typ            |                                                                       |

| Parameter                                  | 25°C  | –40°C to +85°C | –40°C to +125°C    | Unit                                   | Test Conditions/Comments                                                                                                 |
|--------------------------------------------|-------|----------------|--------------------|----------------------------------------|--------------------------------------------------------------------------------------------------------------------------|
| <b>DYNAMIC CHARACTERISTICS<sup>1</sup></b> |       |                |                    |                                        |                                                                                                                          |
| Transition Time, $t_{\text{TRANSITION}}$   | 310   |                |                    | ns typ                                 | $R_L = 300\ \Omega$ , $C_L = 35\ \text{pF}$                                                                              |
|                                            | 410   | 495            | 560                | ns max                                 | $V_S = 3\ \text{V}$ ; see Figure 25                                                                                      |
| $t_{\text{ON}}(\text{EN})$                 | 230   |                |                    | ns typ                                 | $R_L = 300\ \Omega$ , $C_L = 35\ \text{pF}$                                                                              |
|                                            | 305   | 355            | 390                | ns max                                 | $V_S = 3\ \text{V}$ ; see Figure 27                                                                                      |
| $t_{\text{OFF}}(\text{EN})$                | 220   |                |                    | ns typ                                 | $R_L = 300\ \Omega$ , $C_L = 35\ \text{pF}$                                                                              |
|                                            | 290   | 335            | 365                | ns max                                 | $V_S = 3\ \text{V}$ ; see Figure 27                                                                                      |
| Break-Before-Make Time Delay, $t_D$        | 65    |                |                    | ns typ                                 | $R_L = 300\ \Omega$ , $C_L = 35\ \text{pF}$                                                                              |
|                                            |       |                | 31                 | ns min                                 | $V_{S1} = V_{S2} = 3\ \text{V}$ ; see Figure 26                                                                          |
| Charge Injection                           | 59    |                |                    | pC typ                                 | $V_S = 0\ \text{V}$ , $R_S = 0\ \Omega$ , $C_L = 1\ \text{nF}$ ; see Figure 28                                           |
| Off Isolation                              | –60   |                |                    | dB typ                                 | $R_L = 50\ \Omega$ , $C_L = 5\ \text{pF}$ , $f = 1\ \text{MHz}$ ; see Figure 29                                          |
| Channel-to-Channel Crosstalk               | –60   |                |                    | dB typ                                 | $R_L = 50\ \Omega$ , $C_L = 5\ \text{pF}$ , $f = 1\ \text{MHz}$ ; see Figure 30                                          |
| Total Harmonic Distortion Plus Noise       | 0.04  |                |                    | % typ                                  | $R_L = 10\ \text{k}\Omega$ , $5\ \text{V p-p}$ , $f = 20\ \text{Hz to } 20\ \text{kHz}$ ; see Figure 32                  |
| –3 dB Bandwidth                            | 105   |                |                    | MHz typ                                | $R_L = 50\ \Omega$ , $C_L = 5\ \text{pF}$ ; see Figure 31                                                                |
| Insertion Loss                             | 0.28  |                |                    | dB typ                                 | $R_L = 50\ \Omega$ , $C_L = 5\ \text{pF}$ , $f = 1\ \text{MHz}$ ; see Figure 31                                          |
| $C_S(\text{Off})$                          | 26    |                |                    | pF typ                                 | $V_S = 0\ \text{V}$ , $f = 1\ \text{MHz}$                                                                                |
| $C_D(\text{Off})$                          | 62    |                |                    | pF typ                                 | $V_S = 0\ \text{V}$ , $f = 1\ \text{MHz}$                                                                                |
| $C_D, C_S(\text{On})$                      | 128   |                |                    | pF typ                                 | $V_S = 0\ \text{V}$ , $f = 1\ \text{MHz}$                                                                                |
| <b>POWER REQUIREMENTS</b>                  |       |                |                    |                                        |                                                                                                                          |
| $I_{\text{DD}}$                            | 0.001 |                | 1.0                | $\mu\text{A typ}$<br>$\mu\text{A max}$ | $V_{\text{DD}} = +5.5\ \text{V}$ , $V_{\text{SS}} = -5.5\ \text{V}$<br>Digital inputs = $0\ \text{V}$ or $V_{\text{DD}}$ |
| $I_{\text{SS}}$                            | 0.001 |                | 1.0                | $\mu\text{A typ}$<br>$\mu\text{A max}$ | Digital inputs = $0\ \text{V}$ or $V_{\text{DD}}$                                                                        |
| $V_{\text{DD}}/V_{\text{SS}}$              |       |                | $\pm 4.5/\pm 16.5$ | V min/max                              | Ground = $0\ \text{V}$                                                                                                   |

<sup>1</sup> Guaranteed by design, not subject to production test.

## CONTINUOUS CURRENT PER CHANNEL, S OR D

Table 4.

| Parameter                                                    | 25°C | 85°C | 125°C | Unit       | Test Conditions/Comments                                              |
|--------------------------------------------------------------|------|------|-------|------------|-----------------------------------------------------------------------|
| <b>CONTINUOUS CURRENT PER CHANNEL<sup>1</sup></b>            |      |      |       |            |                                                                       |
| ±15 V Dual Supply                                            |      |      |       |            | $V_{\text{DD}} = +13.5\ \text{V}$ , $V_{\text{SS}} = -13.5\ \text{V}$ |
| 8-Lead MSOP ( $\theta_{\text{JA}} = 206^\circ\text{C/W}$ )   | 215  | 135  | 80    | mA maximum |                                                                       |
| 8-Lead LFCSP ( $\theta_{\text{JA}} = 50.8^\circ\text{C/W}$ ) | 390  | 215  | 100   | mA maximum |                                                                       |
| +12 V Single Supply                                          |      |      |       |            | $V_{\text{DD}} = 10.8\ \text{V}$ , $V_{\text{SS}} = 0\ \text{V}$      |
| 8-Lead MSOP ( $\theta_{\text{JA}} = 206^\circ\text{C/W}$ )   | 175  | 115  | 70    | mA maximum |                                                                       |
| 8-Lead LFCSP ( $\theta_{\text{JA}} = 50.8^\circ\text{C/W}$ ) | 320  | 185  | 95    | mA maximum |                                                                       |
| ±5 V Dual Supply                                             |      |      |       |            | $V_{\text{DD}} = +4.5\ \text{V}$ , $V_{\text{SS}} = -4.5\ \text{V}$   |
| 8-Lead MSOP ( $\theta_{\text{JA}} = 206^\circ\text{C/W}$ )   | 165  | 110  | 70    | mA maximum |                                                                       |
| 8-Lead LFCSP ( $\theta_{\text{JA}} = 50.8^\circ\text{C/W}$ ) | 310  | 180  | 95    | mA maximum |                                                                       |

<sup>1</sup> Guaranteed by design, not subject to production test.

## ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$ , unless otherwise noted.

**Table 5.**

| Parameter                                                           | Rating                                                                                 |
|---------------------------------------------------------------------|----------------------------------------------------------------------------------------|
| $V_{DD}$ to $V_{SS}$                                                | 35 V                                                                                   |
| $V_{DD}$ to GND                                                     | –0.3 V to +25 V                                                                        |
| $V_{SS}$ to GND                                                     | +0.3 V to –25 V                                                                        |
| Analog Inputs <sup>1</sup>                                          | $V_{SS} - 0.3\text{ V}$ to $V_{DD} + 0.3\text{ V}$ or<br>30 mA, whichever occurs first |
| Digital Inputs <sup>1</sup>                                         | GND – 0.3 V to $V_{DD} + 0.3\text{ V}$ or<br>30 mA, whichever occurs first             |
| Peak Current, S or D<br>(Pulsed at 1 ms, 10%<br>Duty-Cycle Maximum) |                                                                                        |
| 8-Lead MSOP (4-Layer Board)                                         | 400 mA                                                                                 |
| 8-Lead LFCSP                                                        | 600 mA                                                                                 |
| Continuous Current per<br>Channel, S or D                           | Data in Table 4 + 15% mA                                                               |
| Operating Temperature Range<br>Industrial                           | –40°C to +125°C                                                                        |
| Storage Temperature Range                                           | –65°C to +150°C                                                                        |
| Junction Temperature                                                | 150°C                                                                                  |
| Reflow Soldering Peak<br>Temperature, Pb Free                       | 260°C                                                                                  |

<sup>1</sup> Over voltages at IN, S, or D are clamped by internal diodes. Current should be limited to the maximum ratings given.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

## THERMAL RESISTANCE

**Table 6. Thermal Resistance**

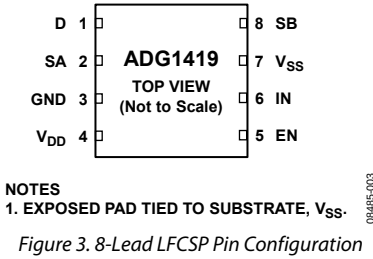
| Package Type                | $\theta_{JA}$ | $\theta_{JC}$ | Unit |
|-----------------------------|---------------|---------------|------|
| 8-Lead MSOP (4-Layer Board) | 206           | 44            | °C/W |
| 8-Lead LFCSP                | 50.8          |               | °C/W |

## ESD CAUTION



**ESD (electrostatic discharge) sensitive device.** Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS



NOTES  
1. EXPOSED PAD TIED TO SUBSTRATE,  $V_{SS}$ .

Figure 3. 8-Lead LFCSP Pin Configuration

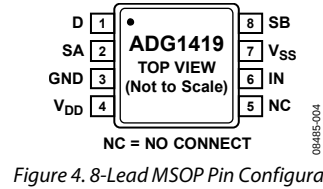


Figure 4. 8-Lead MSOP Pin Configuration

Table 7. Pin Function Descriptions

| Pin No.        |                | Mnemonic | Description                                                                                                                                                                              |
|----------------|----------------|----------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| LFCSP          | MSOP           |          |                                                                                                                                                                                          |
| 1              | 1              | D        | Drain Terminal. This pin can be an input or output.                                                                                                                                      |
| 2              | 2              | SA       | Source Terminal. This pin can be an input or output.                                                                                                                                     |
| 3              | 3              | GND      | Ground (0 V) Reference.                                                                                                                                                                  |
| 4              | 4              | $V_{DD}$ | Most Positive Power Supply Potential.                                                                                                                                                    |
| 5              | Not applicable | EN       | Active High Digital Input. When this pin is low, the device is disabled and all switches are turned off. When this pin is high, the IN logic input determines which switch is turned on. |
| Not applicable | 5              | NC       | No Connect.                                                                                                                                                                              |
| 6              | 6              | IN       | Logic Control Input.                                                                                                                                                                     |
| 7              | 7              | $V_{SS}$ | Most Negative Power Supply Potential.                                                                                                                                                    |
| 8              | 8              | SB       | Source Terminal. This pin can be an input or output.                                                                                                                                     |
| 0              | Not applicable | EPAD     | Exposed Pad. Exposed pad tied to substrate, $V_{SS}$ .                                                                                                                                   |

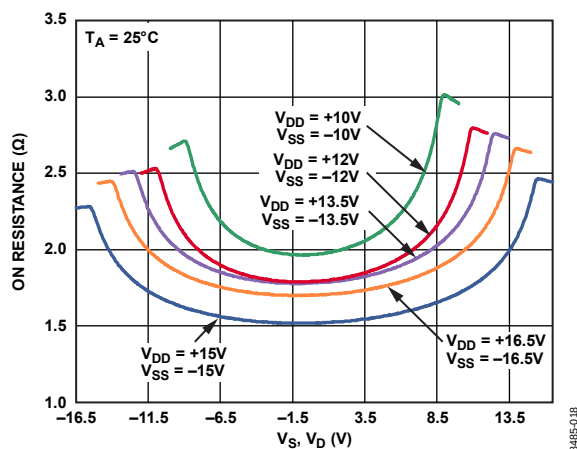
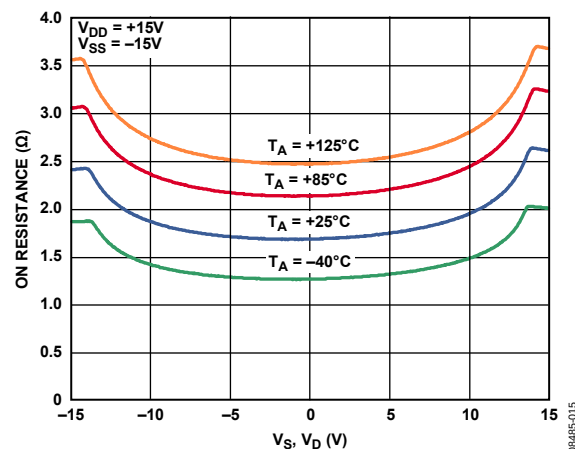
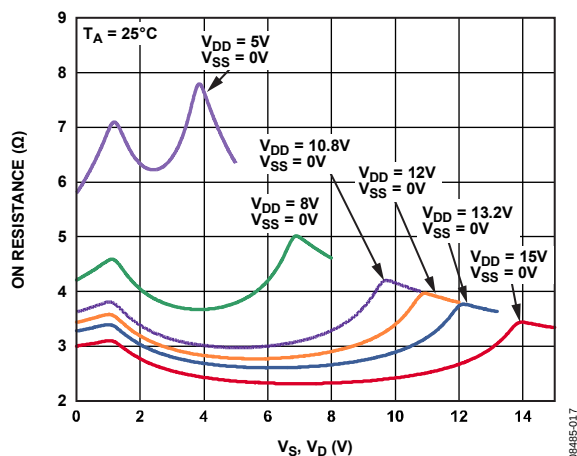
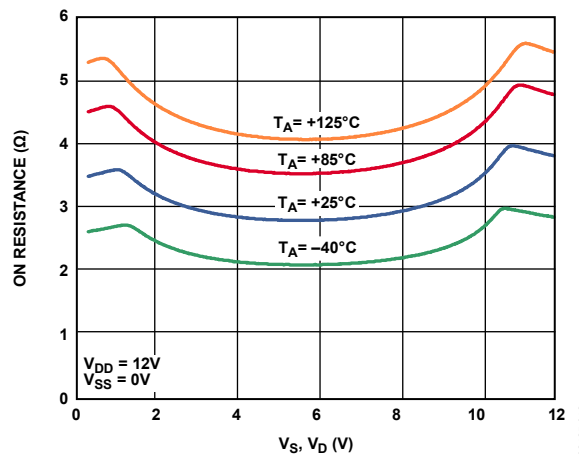
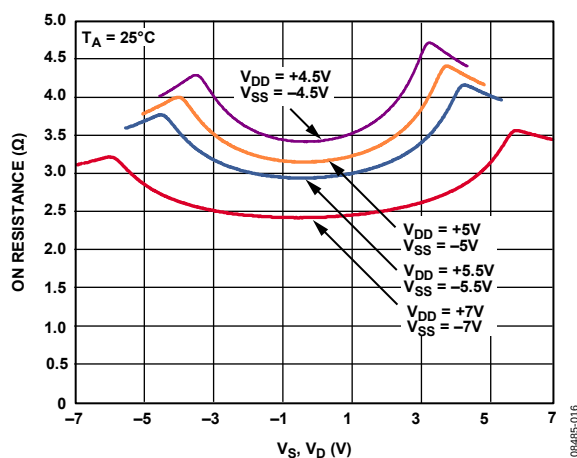
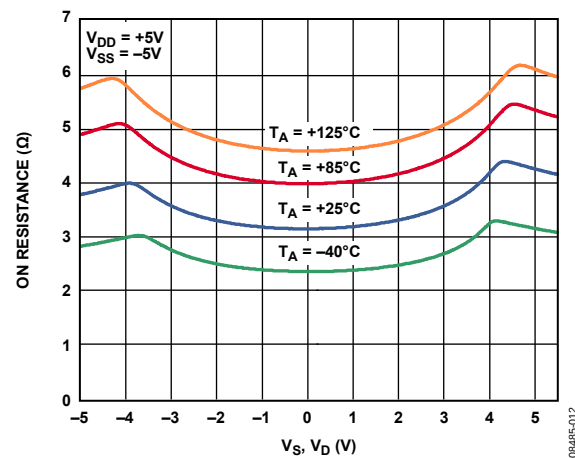
Table 8. 8-Lead LFCSP Truth Table

| EN | IN | Switch A | Switch B |
|----|----|----------|----------|
| 0  | X  | Off      | Off      |
| 1  | 0  | On       | Off      |
| 1  | 1  | Off      | On       |

Table 9. 8-Lead MSOP Truth Table

| IN | Switch A | Switch B |
|----|----------|----------|
| 0  | On       | Off      |
| 1  | Off      | On       |

## TYPICAL PERFORMANCE CHARACTERISTICS

Figure 5. On Resistance as a Function of  $V_D$  ( $V_S$ ) for Dual SupplyFigure 8. On Resistance as a Function of  $V_D$  ( $V_S$ ) for Different Temperatures,  $\pm 15$  V Dual SupplyFigure 6. On Resistance as a Function of  $V_D$  ( $V_S$ ) for Single SupplyFigure 9. On Resistance as a Function of  $V_D$  ( $V_S$ ) for Different Temperatures, +12 V Single SupplyFigure 7. On Resistance as a Function of  $V_D$  ( $V_S$ ) for Dual SupplyFigure 10. On Resistance as a Function of  $V_D$  ( $V_S$ ) for Different Temperatures,  $\pm 5$  V Dual Supply

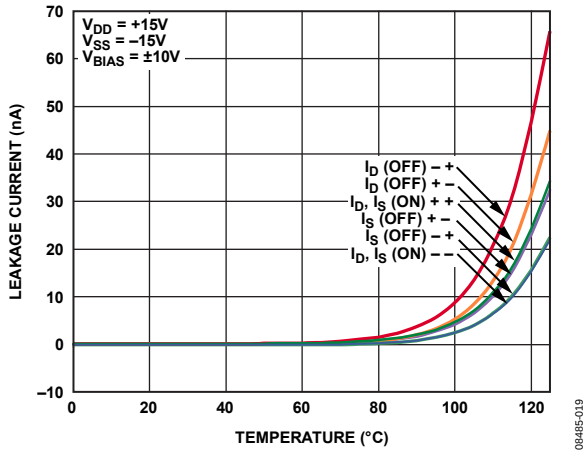


Figure 11. Leakage Currents as a Function of Temperature, ±15 V Dual Supply

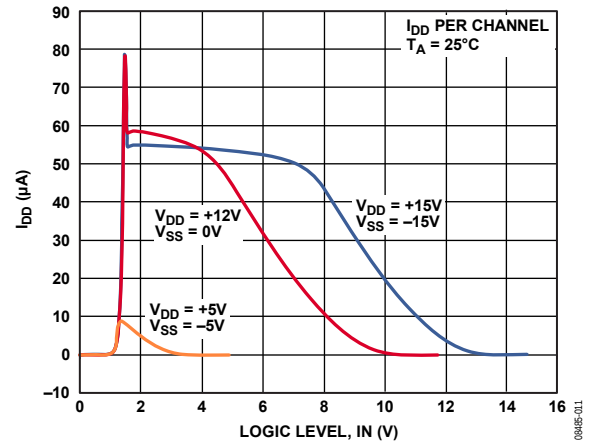


Figure 14.  $I_{DD}$  vs. Logic Level

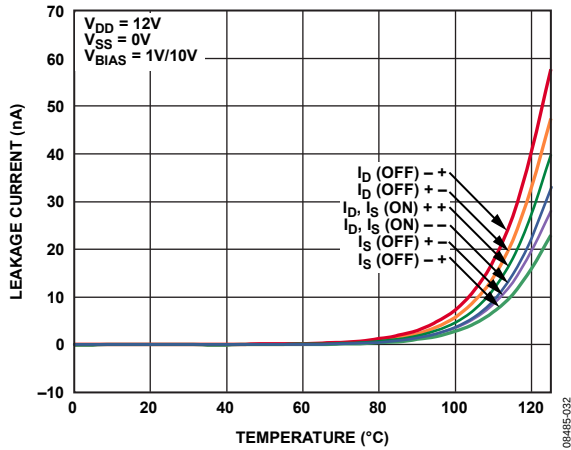


Figure 12. Leakage Currents as a Function of Temperature, +12 V Single Supply

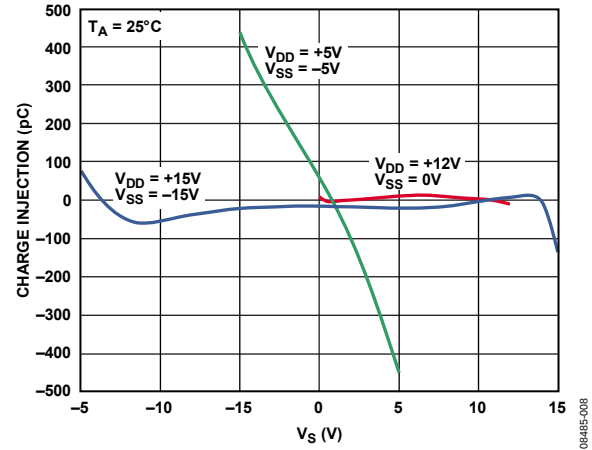


Figure 15. Charge Injection vs. Source Voltage

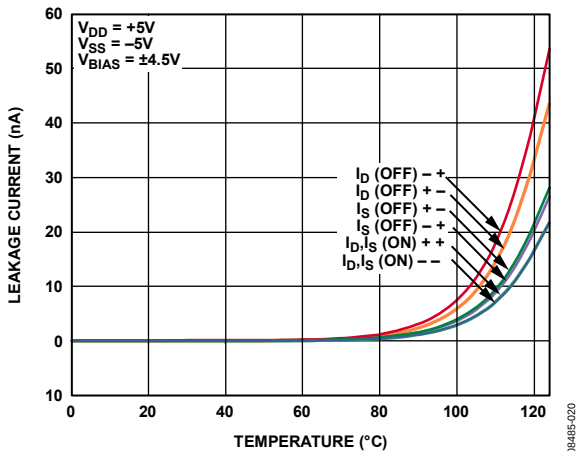


Figure 13. Leakage Currents as a Function of Temperature, ±5 V Dual Supply

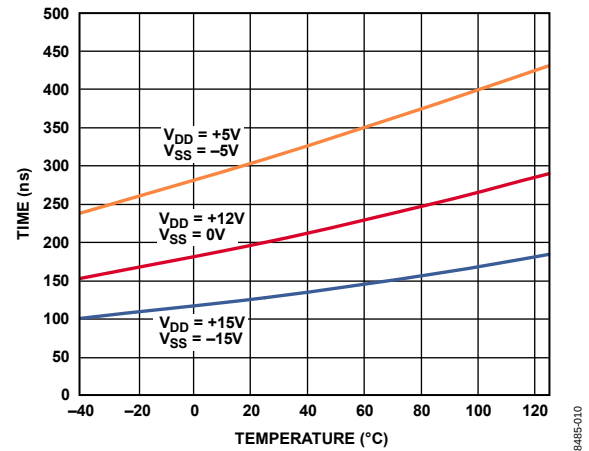


Figure 16.  $t_{TRANSITION}$  Times vs. Temperature

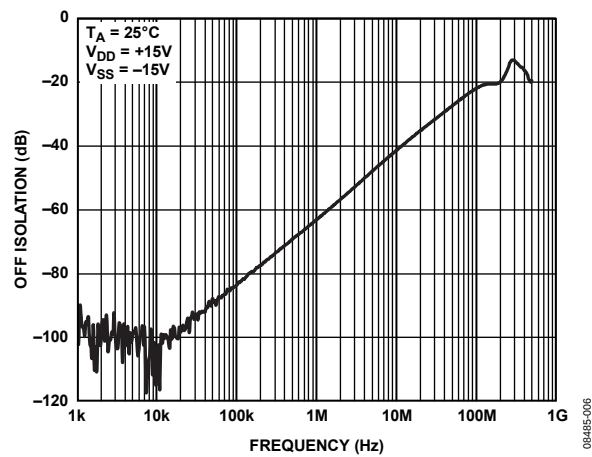


Figure 17. Off Isolation vs. Frequency

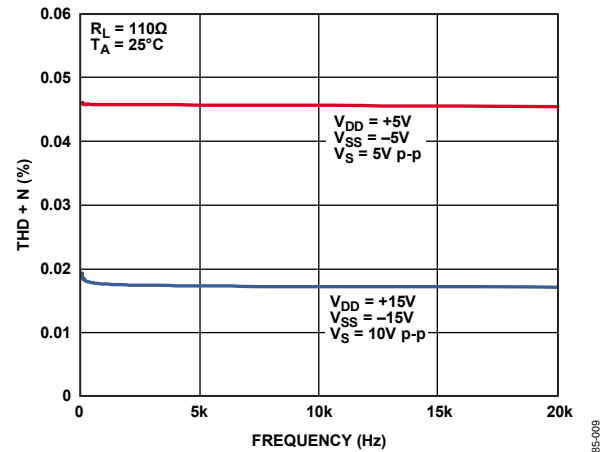


Figure 20. THD + N vs. Frequency

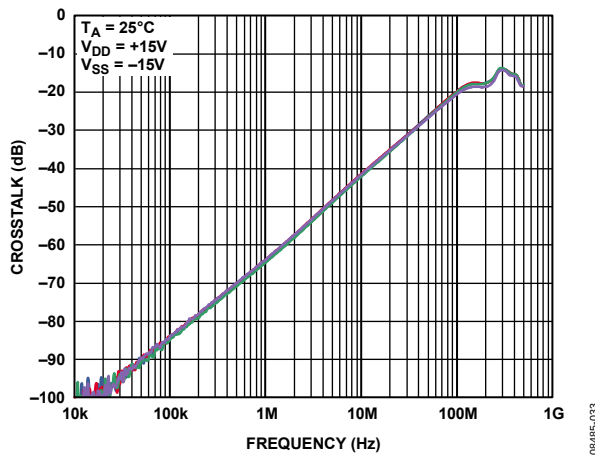


Figure 18. Crosstalk vs. Frequency

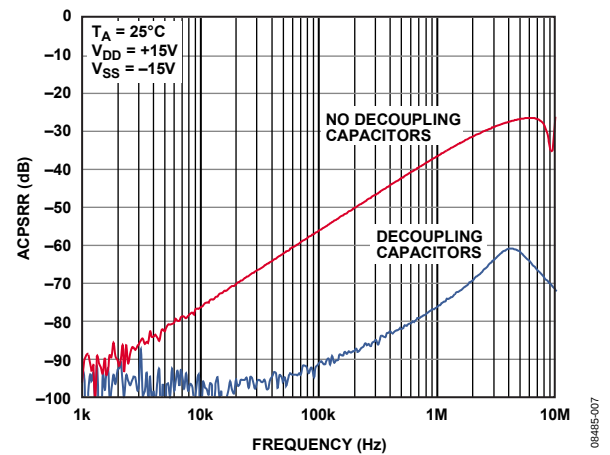


Figure 21. ACPSRR vs. Frequency

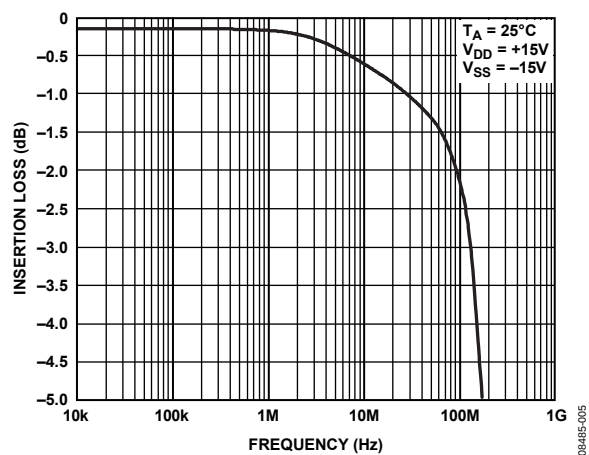


Figure 19. On Response vs. Frequency

## TEST CIRCUITS

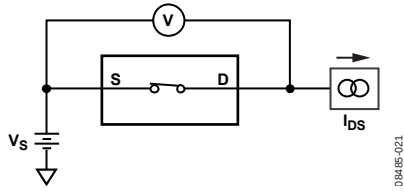


Figure 22. On Resistance

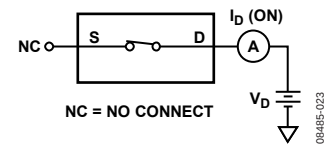


Figure 24. On Leakage

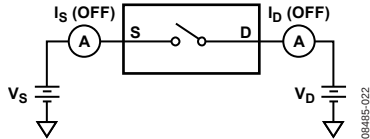


Figure 23. Off Leakage

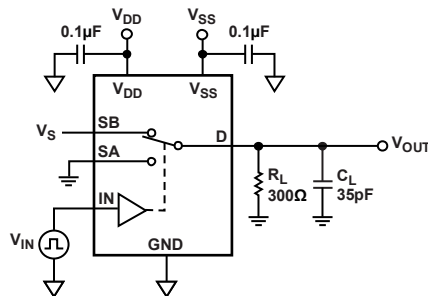


Figure 25. Switching Times,  $t_{ON}$  and  $t_{OFF}$

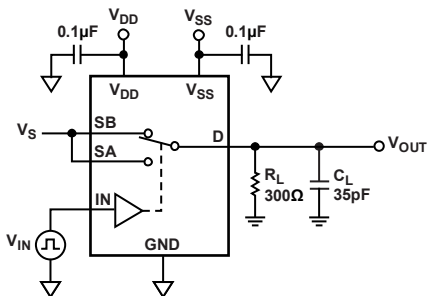
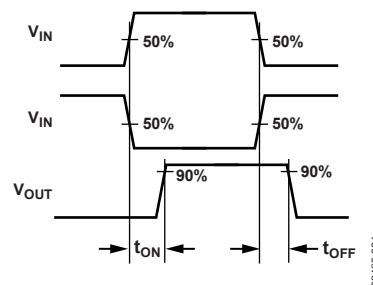


Figure 26. Break-Before-Make Time Delay

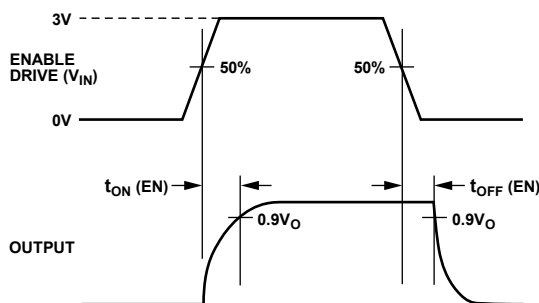
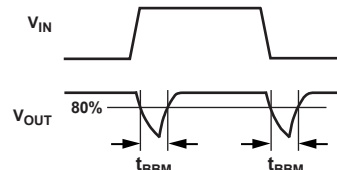
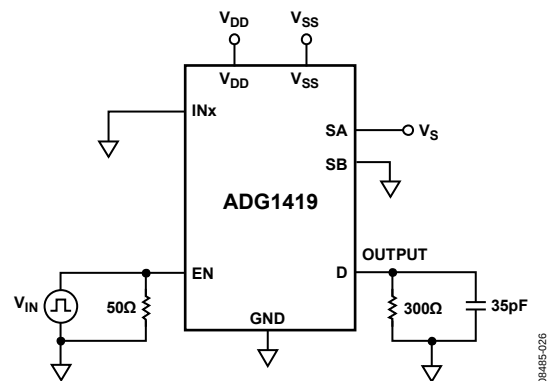


Figure 27. Enable Delay,  $t_{ON} (EN)$ ,  $t_{OFF} (EN)$



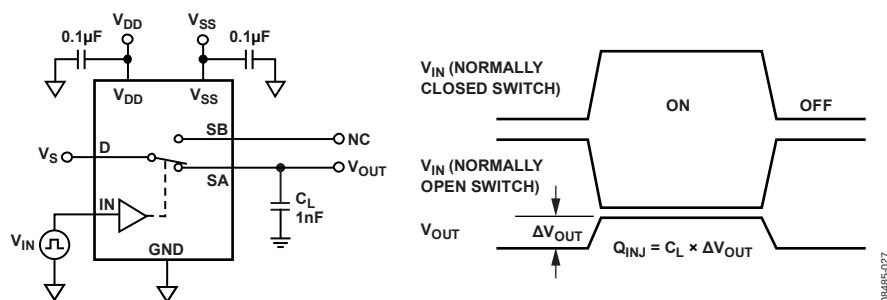


Figure 28. Charge Injection

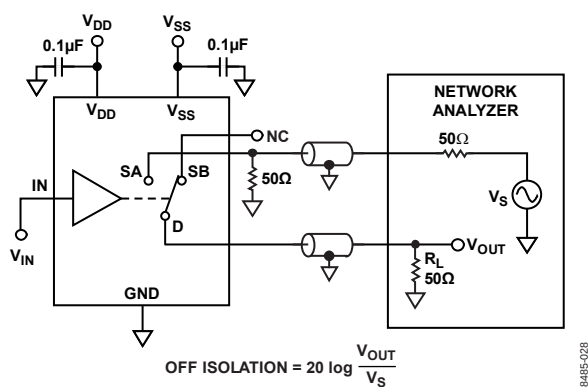


Figure 29. Off Isolation

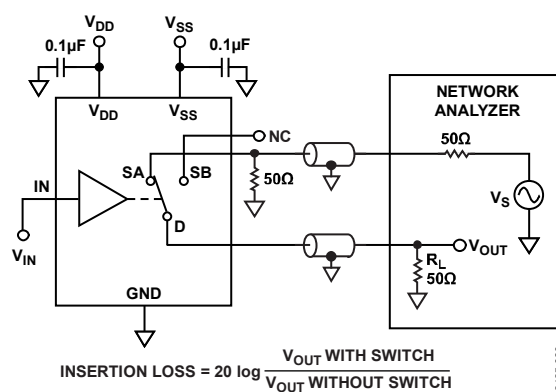


Figure 31. Bandwidth

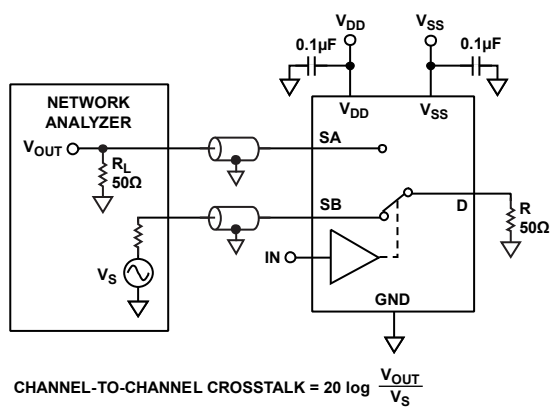


Figure 30. Channel-to-Channel Crosstalk

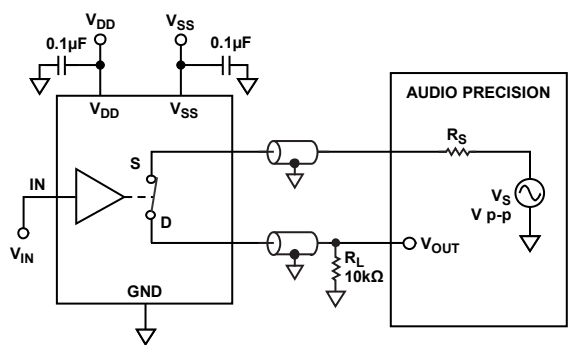


Figure 32. THD + N

## TERMINOLOGY

### **I<sub>DD</sub>**

The positive supply current.

### **I<sub>SS</sub>**

The negative supply current.

### **V<sub>D</sub> (V<sub>S</sub>)**

The analog voltage on Terminal D and Terminal S.

### **R<sub>ON</sub>**

The ohmic resistance between Terminal D and Terminal S.

### **R<sub>FLAT</sub> (ON)**

Flatness is defined as the difference between the maximum and minimum value of on resistance as measured over the specified analog signal range.

### **I<sub>S</sub> (Off)**

The source leakage current with the switch off.

### **I<sub>D</sub> (Off)**

The drain leakage current with the switch off.

### **I<sub>D</sub>, I<sub>S</sub> (On)**

The channel leakage current with the switch on.

### **V<sub>INL</sub>**

The maximum input voltage for Logic 0.

### **V<sub>INH</sub>**

The minimum input voltage for Logic 1.

### **I<sub>INL</sub> (I<sub>INH</sub>)**

The input current of the digital input.

### **C<sub>S</sub> (Off)**

The off switch source capacitance, measured with reference to ground.

### **C<sub>D</sub> (Off)**

The off switch drain capacitance, measured with reference to ground.

### **C<sub>D</sub>, C<sub>S</sub> (On)**

The on switch capacitance, measured with reference to ground.

### **C<sub>IN</sub>**

The digital input capacitance.

### **t<sub>ON</sub> (EN)**

Delay time between the 50% and 90% points of the digital input and switch on condition. See Figure 27.

### **t<sub>OFF</sub> (EN)**

Delay time between the 50% and 90% points of the digital input and switch off condition. See Figure 27.

### **t<sub>TRANSITION</sub>**

Delay time between the 50% and 90% points of the digital inputs and the switch on condition when switching from one address state to another.

### **T<sub>BBM</sub>**

Off time measured between the 80% point of both switches when switching from one address state to another. See Figure 26.

### **Charge Injection**

A measure of the glitch impulse transferred from the digital input to the analog output during switching. See Figure 28.

### **Off Isolation**

A measure of unwanted signal coupling through an off switch. See Figure 29.

### **Crosstalk**

A measure of unwanted signal that is coupled through from one channel to another as a result of parasitic capacitance. See Figure 30.

### **Bandwidth**

The frequency at which the output is attenuated by 3 dB. See Figure 31.

### **On Response**

The frequency response of the on switch.

### **Insertion Loss**

The loss due to the on resistance of the switch. See Figure 31.

### **THD + N**

The ratio of the harmonic amplitude plus noise of the signal to the fundamental. See Figure 32.

### **AC Power Supply Rejection Ratio (ACPSRR)**

ACPSRR measures the ability of a part to avoid coupling noise and spurious signals that appear on the supply voltage pin to the output of the switch. The dc voltage on the device is modulated by a sine wave of 0.62 V p-p. The ratio of the amplitude of signal on the output to the amplitude of the modulation is the ACPSRR. See Figure 21.

## OUTLINE DIMENSIONS

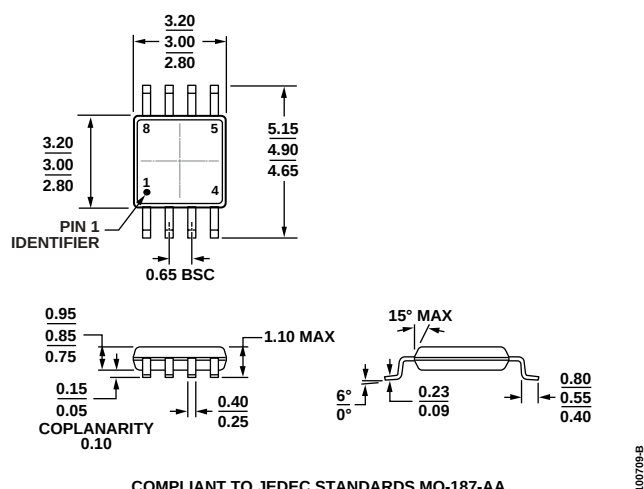


Figure 33. 8-Lead Mini Small Outline Package [MSOP]  
(RM-8)

Dimensions shown in millimeters

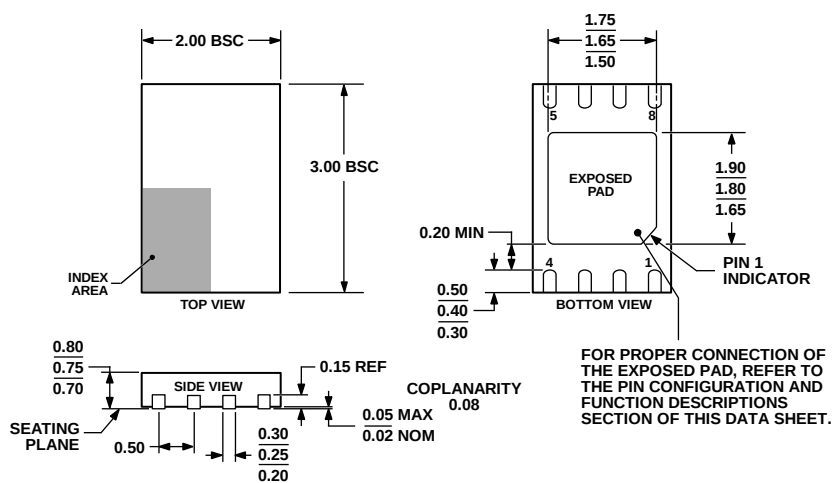


Figure 34. 8-Lead Lead Frame Chip Scale Package [LFCSP\_WD]  
3 mm x 2 mm Body, Very Very Thin, Dual Lead  
(CP-8-4)

Dimensions shown in millimeters

## ORDERING GUIDE

| Model <sup>1</sup> | Temperature Range | Package Description                             | Package Option | Branding |
|--------------------|-------------------|-------------------------------------------------|----------------|----------|
| ADG1419BRMZ        | −40°C to +125°C   | 8-Lead Mini Small Outline Package [MSOP]        | RM-8           | S1L      |
| ADG1419BRMZ-REEL7  | −40°C to +125°C   | 8-Lead Mini Small Outline Package [MSOP]        | RM-8           | S1L      |
| ADG1419BCPZ-REEL7  | −40°C to +125°C   | 8-Lead Lead Frame Chip Scale Package [LFCSP_WD] | CP-8-4         | 1C       |

<sup>1</sup> Z = RoHS Compliant Part.

**NOTES**

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



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